

LP324-N/LP2902-N Micropower Quad Operational Amplifier

Check for Samples: [LP2902-N](#), [LP324-N](#)

FEATURES

- **Low Supply Current:** 85µA (typ)
- **Low Offset Voltage:** 2mV (typ)
- **Low Input Bias Current:** 2nA (typ)
- **Input Common Mode to GND**
- **Interfaces to CMOS Logic**
- **Wide Supply Range:** $3V < V^+ < 32V$
- **Small Outline Package Available**
- **Pin-for-pin Compatible with LM324**

DESCRIPTION

The LP324-N series consists of four independent, high gain internally compensated micropower operational amplifiers. These amplifiers are specially suited for operation in battery systems while maintaining good input specifications, and extremely low supply current drain. In addition, the LP324-N has an input common mode range, and output source range which includes ground, making it ideal in single supply applications.

These amplifiers are ideal in applications which include portable instrumentation, battery backup equipment, and other circuits which require good DC performance and low supply current.

Connection Diagram

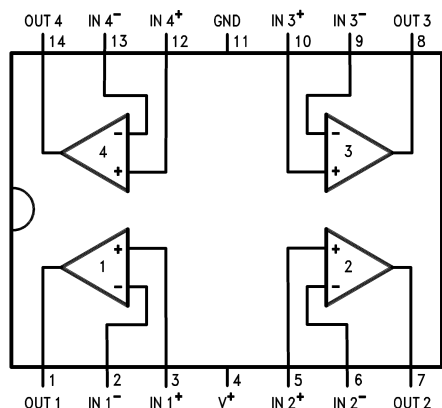


Figure 1. 14-Lead SOIC
See NFF0014A or D Package

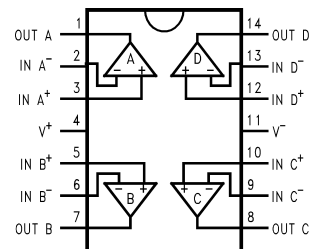


Figure 2. 14-Pin TSSOP
See PW Package



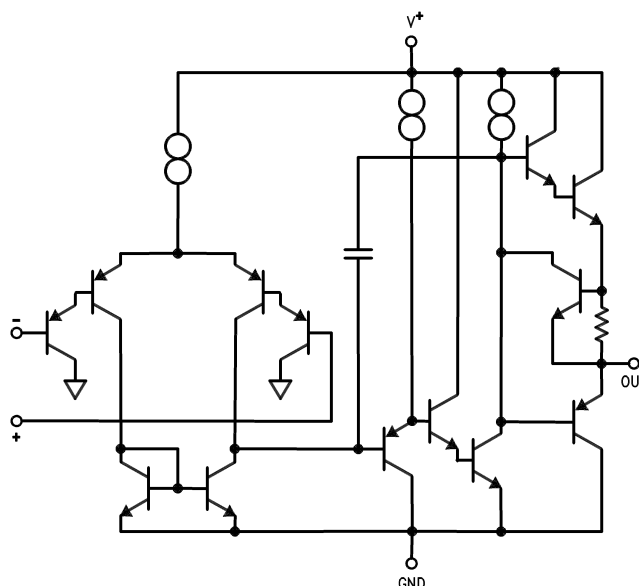
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

Copyright © 1999–2013, Texas Instruments Incorporated

Simplified Schematic



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings⁽¹⁾⁽²⁾

Supply Voltage	LP324-N	32V or $\pm 16V$
	LP2902-N	26V or $\pm 13V$
Differential Input Voltage	LP324-N	32V
	LP2902-N	26V
Input Voltage ⁽³⁾	LP324-N	$-0.3V$ to 32V
	LP2902-N	$-0.3V$ to 26V
Output Short-Circuit to GND (One Amplifier) ⁽⁴⁾		Continuous
$V^+ \leq 15V$ and $T_A = 25^\circ C$	ESD Susceptibility ⁽⁵⁾	$\pm 500V$

- (1) "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (3) The input voltage is not allowed to go more than $-0.3V$ below V^- (GND) as this will turn on a parasitic transistor causing large currents to flow through the device.
- (4) Short circuits from the output to GND can cause excessive heating and eventual destruction. The maximum sourcing output current is approximately 30 mA independent of the magnitude of V^+ . At values of supply voltage in excess of $15 V_{DC}$, continuous short-circuit to GND can exceed the power dissipation ratings (particularly at elevated temperatures) and cause eventual destruction. Destructive dissipation can result from simultaneous shorts on all amplifiers.
- (5) The test circuit used consists of the human body model of 100 pF in series with 1500 Ω .

Operating Conditions

T_{JMAX}		150°C
$\theta_{JA}^{(1)}$	PW Package	154°C/W
	NFF014A Package	90°C/W
	D Package	140°C/W
Operating Temp. Range		See ⁽²⁾
Storage Temp. Range		-65°C ≤ T _J ≤ 150°C
Soldering Information	Wave Soldering(10sec)	260°C(lead temp.)
	Convection or Infrared(20sec)	235°C

(1) For operation at elevated temperatures, these devices must be derated based on a thermal resistance of θ_{JA} and T_J max. T_J = T_A + $\theta_{JA}P_D$.

(2) The LP2902-N may be operated from -40°C ≤ T_A ≤ +85°C, and the LP324-N may be operated from 0°C ≤ T_A ≤ +70°C.

Electrical Characteristics⁽¹⁾

Symbol	Parameter	Conditions	LP2902-N ⁽²⁾			LP324-N			Units Limits
			Typ	Tested Limit ⁽³⁾	Design Limit ⁽⁴⁾	Typ	Tested Limit ⁽³⁾	Design Limit ⁽⁴⁾	
V _{OS}	Input Offset Voltage		2	4	10	2	4	9	mV (Max)
I _B	Input Bias Current		2	20	40	2	10	20	nA (Max)
I _{OS}	Input Offset Current		0.5	4	8	0.2	2	4	nA (Max)
A _{VOL}	Voltage Gain	R _L = 10k to GND V ⁺ = 30V	70	40	30	100	50	40	V/mV (Min)
CMRR	Common Mode Rej. Ratio	V ⁺ = 30V, 0V ≤ V _{CM} V _{CM} < V ⁺ - 1.5	90	80	75	90	80	75	dB (Min)
PSRR	Power Supply Rej. Ratio	V ⁺ = 5V to 30V	90	80	75	90	80	75	dB (Min)
I _S	Supply Current	R _L = ∞	85	150	250	85	150	250	μA (Max)
V _O	Output Voltage Swing	I _L = 350μA to GND V _{CM} = 0V	3.6	3.4	V⁺-1.9V	3.6	3.4	V⁺-1.9V	V (Min)
		I _L = 350μA to V ⁺ V _{CM} = 0V	0.7	0.8	1.0	0.7	0.8	1.0	V (Max)
I _{OUT Source}	Output Source Current	V _O = 3V V _{IN} (diff) = 1V	10	7	4	10	7	4	mA (Min)
I _{OUT Sink}	Output Sink Current	V _O = 1.5V V _{IN} (diff) = 1V	5	4	3	5	4	3	mA (Min)
I _{OUT Sink}	Output Sink Current	V _O = 1.5V V _{CM} = 0V	4	2	1	4	2	1	mA (Min)
I _{SOURCE}	Output Short to GND	V _{IN} (diff) = 1V	20	25 35	35	20	25 35	35	mA (Max)
I _{SINK}	Output Short to V ⁺	V _{IN} (diff) = 1V	15	30	45	15	30	45	mA (Max)
V _{OS} Drift			10			10			μV/C°
I _{OS} Drift			10			10			pA/C°
GBW	Gain Bandwidth Product		100			100			KHz
SR	Slew Rate		50			50			V/mS

(1) **Boldface** numbers apply at temperature extremes. All other numbers apply only at T_A = T_J = 25°C, V⁺ = 5V, V_{cm} = V/2, and R_L = 100k connected to GND unless otherwise specified.

(2) The LP2902-N operating supply range is 3V to 26V, and is not tested above 26V.

(3) Specified and 100% production tested.

(4) Specified (but not 100% production tested) over the operating supply voltage range (3.0V to 32V for the LP324-N, LP324-N, and 3.0V to 26V for the LP2902-N), and the common mode range (0V to V⁺ - 1.5V), unless otherwise specified. These limits are not used to calculate outgoing quality levels.

Typical Performance Curves

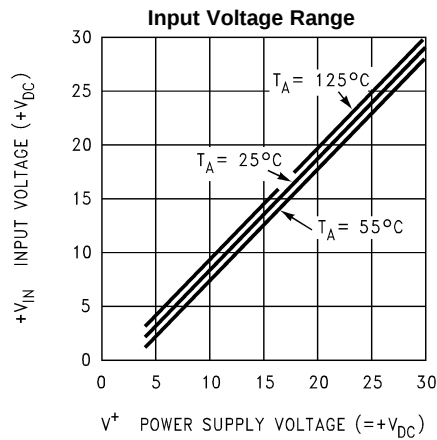


Figure 3.

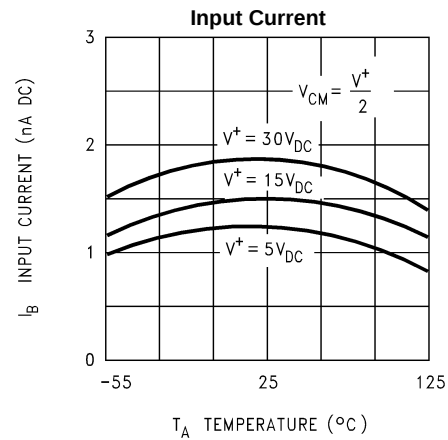


Figure 4.

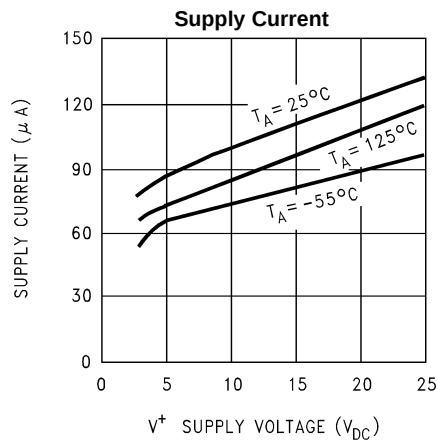


Figure 5.

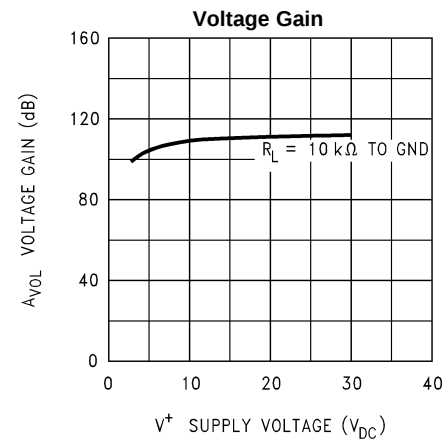


Figure 6.

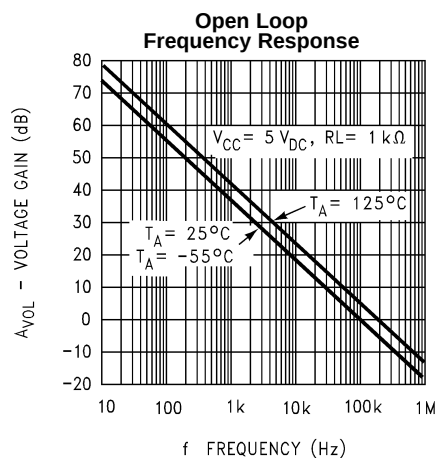


Figure 7.

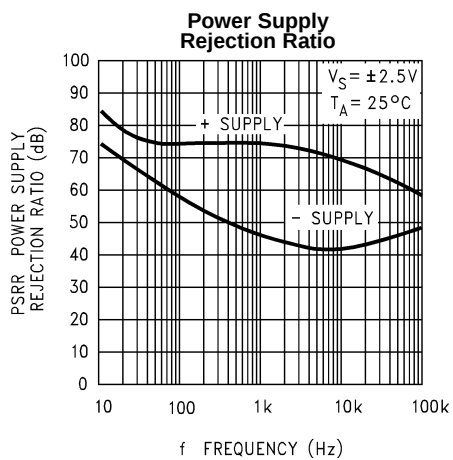


Figure 8.

Typical Performance Curves (continued)

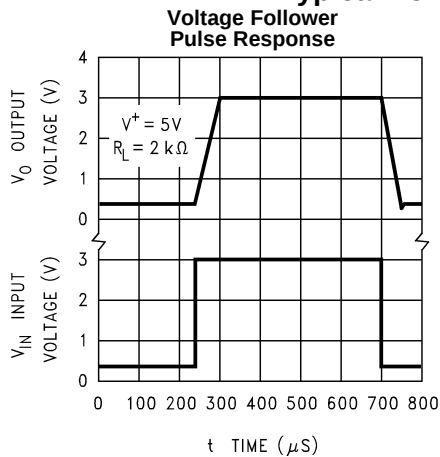


Figure 9.

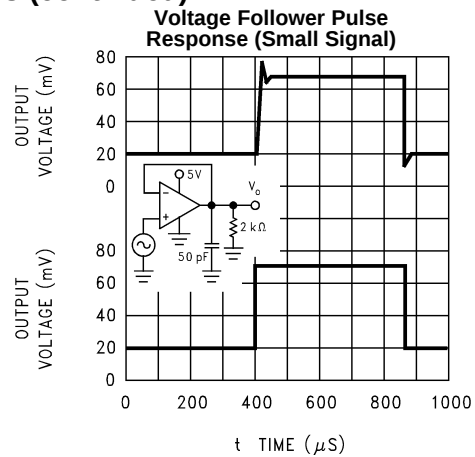


Figure 10.

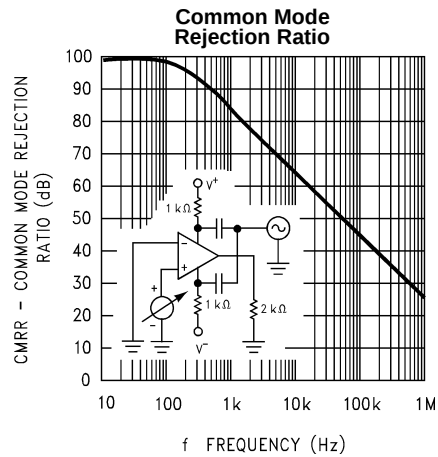


Figure 11.

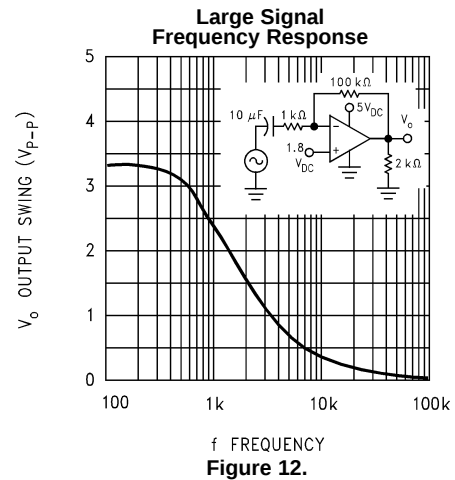


Figure 12.

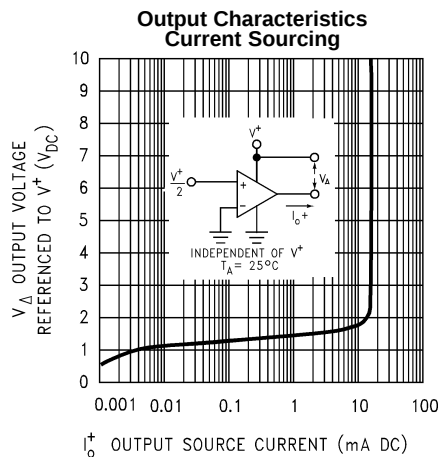


Figure 13.

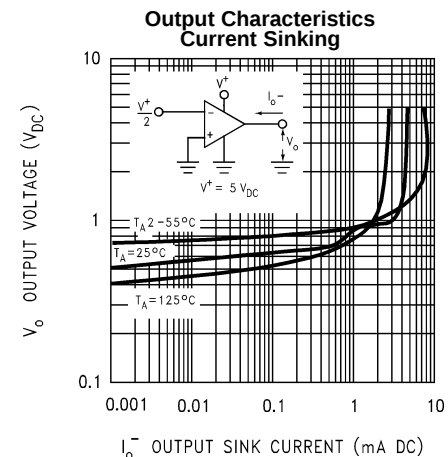


Figure 14.

Typical Performance Curves (continued)

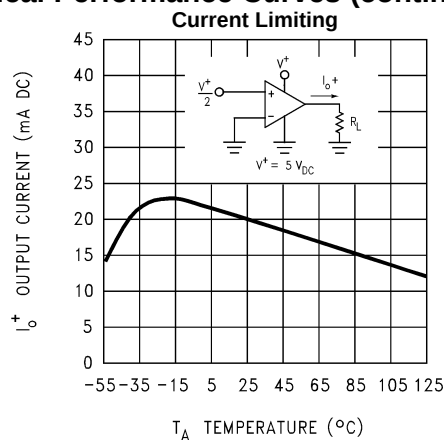


Figure 15.

APPLICATION HINTS

The LP324-N series is a micro-power pin-for-pin equivalent to the LM324 op amps. Power supply current, input bias current, and input offset current have all been reduced by a factor of 10 over the LM324. Like its predecessor, the LP324-N series op amps can operate on single supply, have true-differential inputs, and remain in the linear mode with an input common-mode voltage of 0 V_{DC}.

The pinouts of the package have been designed to simplify PC board layouts. Inverting inputs are adjacent to outputs for all of the amplifiers and the outputs have also been placed at the corners of the package (pins 1, 7, 8, and 14).

Precautions should be taken to insure that the power supply for the integrated circuit never becomes reversed in polarity or the unit is not inadvertently installed backwards in the test socket as an unlimited current surge through the resulting forward diode within the IC could destroy the unit.

Large differential input voltages can be easily accommodated and, as input differential voltage protection diodes are not needed, no large input currents result from large differential input voltages. The differential input voltage may be larger than V⁺ without damaging the device. Protection should be provided to prevent the input voltages from going negative more than -0.3 V_{DC} (at 25°C). An input clamp diode with a resistor to the IC input terminal can be used.

The amplifiers have a class B output stage which allows the amplifiers to both source and sink output currents. In applications where crossover distortion is undesirable, a resistor should be used from the output of the amplifier to ground. The resistor biases the output into class A operation.

The LP324-N has improved stability margin for driving capacitive loads. No special precautions are needed to drive loads in the 50 pF to 1000 pF range. It should be noted however that since the power supply current has been reduced by a factor of 10, so also has the slew rate and gain bandwidth product. This reduction can cause reduced performance in AC applications where the LM324 is being replaced by an LP324-N. Such situations usually occur when the LM324 has been operated near its power bandwidth.

Output short circuits either to ground or to the positive power supply should be of short time duration. Units can be destroyed, not as a result of the short circuit current causing metal fusing, but rather due to the large increase in IC chip dissipation which will cause eventual failure due to excessive junction temperatures. For example: If all four amplifiers were simultaneously shorted to ground on a 10V supply the junction temperature would rise by 110°C.

Exceeding the negative common-mode limit on either input will cause a reversal of phase to the output and force the amplifier to the corresponding high or low state. Exceeding the negative common-mode limit on both inputs will force the amplifier output to a high state. Exceeding the positive common-mode limit on a single input will not change the phase of the output. However, if both inputs exceed the limit, the output of the amplifier will be forced to a low state. In neither case does a latch occur since returning the input within the common mode range puts the input stage and thus the amplifier in a normal operating mode.

The circuits presented in the section on typical applications emphasize operation on only a single power supply voltage. If complementary power supplies are available, all of the standard op amp circuits can be used. In general, introducing a pseudo-ground (a bias voltage reference to $V^+/2$) will allow operation above and below this value in single power supply systems. Many application circuits are shown which take advantage of the wide input common-mode voltage range which includes ground. In most cases, input biasing is not required and input voltages which range to ground can easily be accommodated.

Figure 16. Driving CMOS

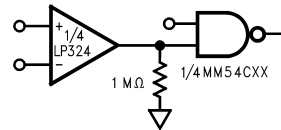


Figure 17. Comparator with Hysteresis

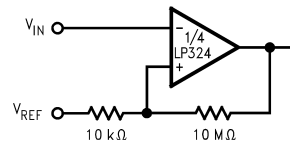


Figure 18. Non-Inverting Amplifier

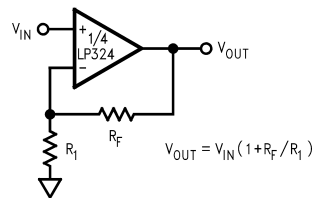


Figure 19. Adder/Subtractor

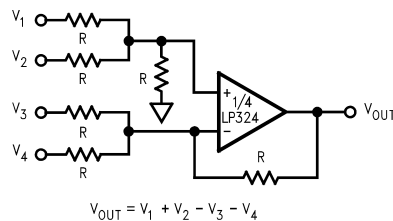


Figure 20. Unity Gain Buffer

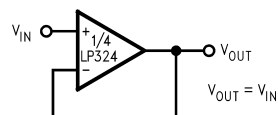


Figure 21. Positive Integrator

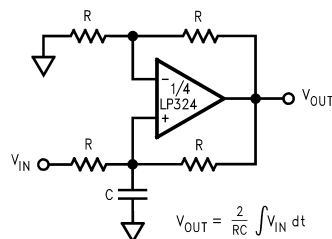


Figure 22. Differential Integrator

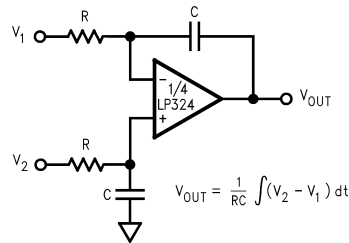


Figure 23. Howland Current Pump

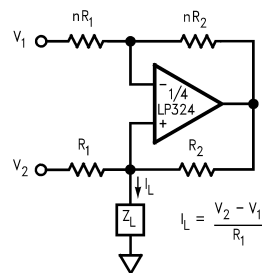


Figure 24. Bridge Current Amplifier

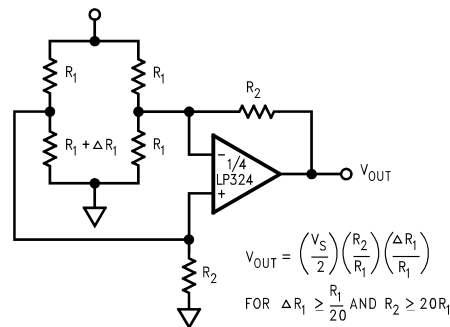


Figure 25. μ Power Current Source

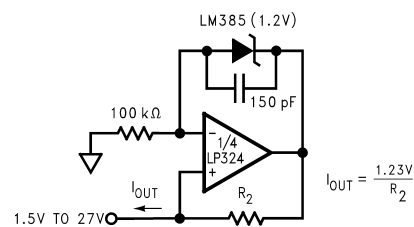


Figure 26. Lowpass Filter

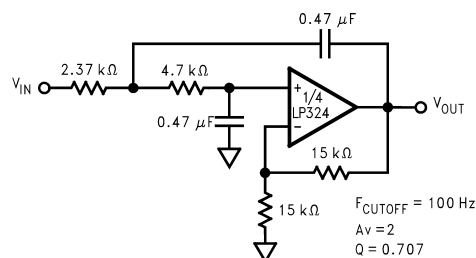


Figure 27. 1 kHz Bandpass Active Filter

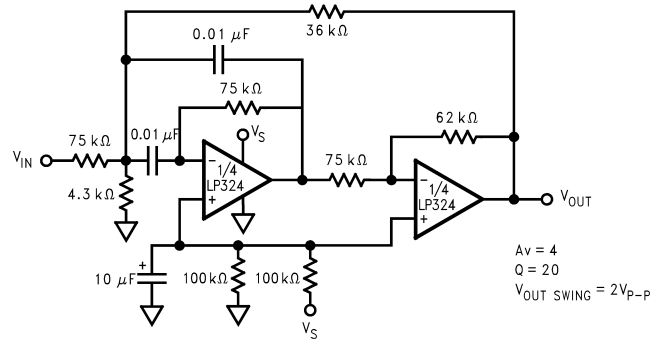


Figure 28. Band-Reject Filter

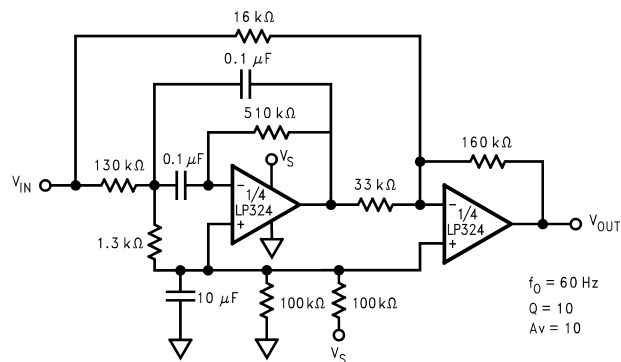


Figure 29. Pulse Generator

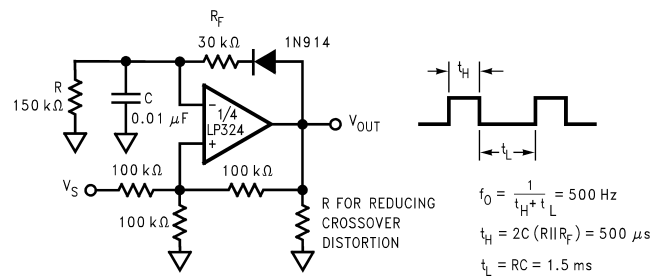
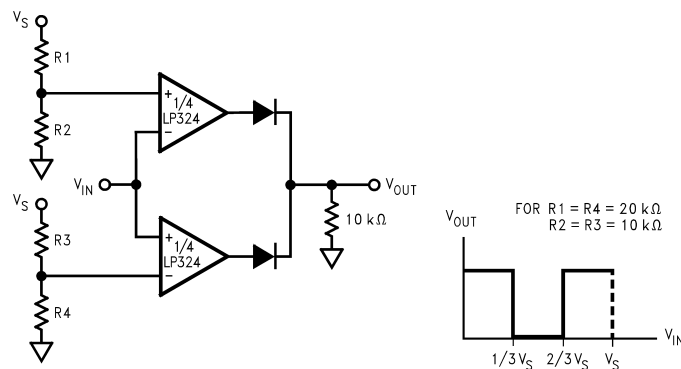


Figure 30. Window Comparator



REVISION HISTORY

Changes from Revision B (March 2013) to Revision C	Page
Changed layout of National Data Sheet to TI format	9

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
LP2902M	ACTIVE	SOIC	D	14	55	TBD	Call TI	Call TI	-40 to 85	LP2902M	Samples
LP2902M/NOPB	ACTIVE	SOIC	D	14	55	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LP2902M	Samples
LP2902MX	ACTIVE	SOIC	D	14	2500	TBD	Call TI	Call TI	-40 to 85	LP2902M	Samples
LP2902MX/NOPB	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LP2902M	Samples
LP2902N/NOPB	ACTIVE	PDIP	NFF	14	25	Green (RoHS & no Sb/Br)	CU SN	Level-1-NA-UNLIM	-40 to 85	LP2902N	Samples
LP2902N/PB	ACTIVE	PDIP	NFF	14	25	TBD	Call TI	Call TI		LP2902N	Samples
LP324M	ACTIVE	SOIC	D	14	55	TBD	Call TI	Call TI	0 to 70	LP324M	Samples
LP324M/NOPB	ACTIVE	SOIC	D	14	55	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 70	LP324M	Samples
LP324MT	ACTIVE	TSSOP	PW	14	94	TBD	Call TI	Call TI	0 to 70	LP324 MT	Samples
LP324MT/NOPB	ACTIVE	TSSOP	PW	14	94	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 70	LP324 MT	Samples
LP324MTX	ACTIVE	TSSOP	PW	14	2500	TBD	Call TI	Call TI	0 to 70	LP324 MT	Samples
LP324MTX/NOPB	ACTIVE	TSSOP	PW	14	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 70	LP324 MT	Samples
LP324MX	ACTIVE	SOIC	D	14	2500	TBD	Call TI	Call TI	0 to 70	LP324M	Samples
LP324MX/NOPB	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 70	LP324M	Samples
LP324N/NOPB	ACTIVE	PDIP	NFF	14	25	Green (RoHS & no Sb/Br)	CU SN	Level-1-NA-UNLIM	0 to 70	LP324N	Samples
LP324N/PB	ACTIVE	PDIP	NFF	14	25	TBD	Call TI	Call TI		LP324N	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LP2902MX	SOIC	D	14	2500	330.0	16.4	6.5	9.35	2.3	8.0	16.0	Q1
LP2902MX/NOPB	SOIC	D	14	2500	330.0	16.4	6.5	9.35	2.3	8.0	16.0	Q1
LP324MTX	TSSOP	PW	14	2500	330.0	12.4	6.95	8.3	1.6	8.0	12.0	Q1
LP324MTX/NOPB	TSSOP	PW	14	2500	330.0	12.4	6.95	8.3	1.6	8.0	12.0	Q1
LP324MX	SOIC	D	14	2500	330.0	16.4	6.5	9.35	2.3	8.0	16.0	Q1
LP324MX/NOPB	SOIC	D	14	2500	330.0	16.4	6.5	9.35	2.3	8.0	16.0	Q1

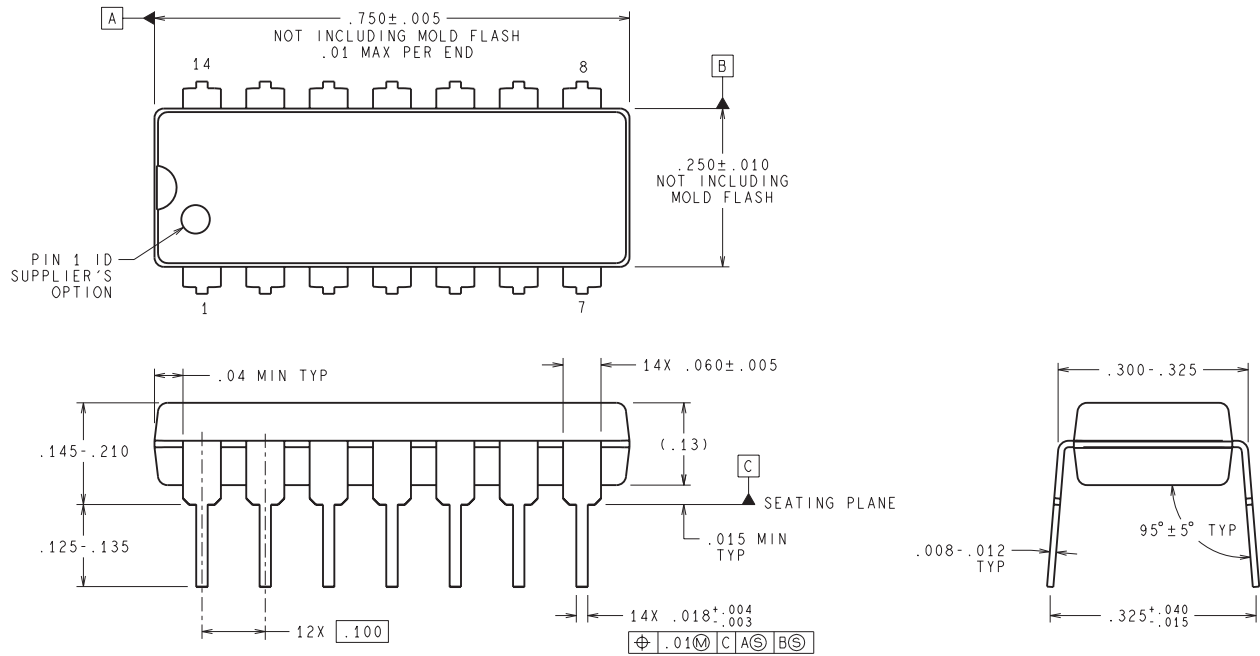
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LP2902MX	SOIC	D	14	2500	367.0	367.0	35.0
LP2902MX/NOPB	SOIC	D	14	2500	367.0	367.0	35.0
LP324MTX	TSSOP	PW	14	2500	367.0	367.0	35.0
LP324MTX/NOPB	TSSOP	PW	14	2500	367.0	367.0	35.0
LP324MX	SOIC	D	14	2500	367.0	367.0	35.0
LP324MX/NOPB	SOIC	D	14	2500	367.0	367.0	35.0

NFF0014A



DIMENSIONS ARE IN INCHES
DIMENSIONS IN () FOR REFERENCE ONLY

N14A (Rev G)

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



4040047-5/M 06/11

NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com